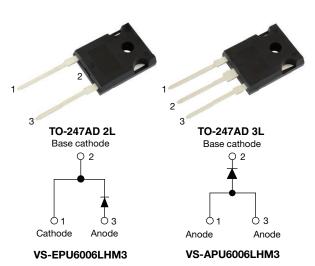


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Vishay Semiconductors

Ultrafast Soft Recovery Diode, 60 A FRED Pt®



PRIMARY CHARACTERISTICS						
I _{F(AV)}	60 A					
V_R	600 V					
V _F at I _F	1.05 V					
t _{rr} typ.	32 ns					
T _J max.	175 °C					
Package	TO-247AD 2L, TO-247AD 3L					
Circuit configuration	Single					

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- AEC-Q101 qualified meets JESD 201 class 1 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



DESCRIPTION / APPLICATIONS

VS-EPU60... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, welding, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V_{RRM}		600	V			
Average rectified forward current in DC	I _{F(AV)}	T _C = 116 °C	60	Α			
Single pulse forward current	I _{FSM}	$T_C = 25$ °C, $t_p = 8.3$ ms; half sine wave	600	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP. MAX				UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage		I _F = 60 A	-	1.2	1.5	V
	V_{F}	I _F = 60 A, T _J = 125 °C	-	1.1	1.3	
		I _F = 60 A, T _J = 175 °C	-	1.05	1.2	
Reverse leakage current		V _R = V _R rated	-	0.2	30	
	I _R	T _J = 150 °C, V _R = V _R rated	-	-	200	μΑ
Junction capacitance	C _T	V _R = 600 V	-	38	-	pF



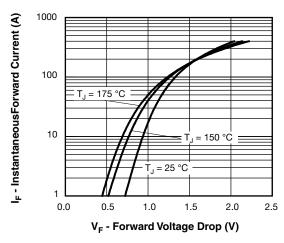
VS-EPU6006LHN3, VS-APU6006LHN3

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 A, di_F/dt = 20$	00 A/μs, V _R = 30 V	-	32	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	110	-	ns	
		T _J = 125 °C	I _F = 60 A di _F /dt = 200 A/µs V _R = 200 V	-	200	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		=	10	-	^	
		T _J = 125 °C		=	19	-	А	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		=	530	-		
		T _J = 125 °C		-	1900	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	0.65		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W	
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Woiselpt			-	6	-	g	
Weight			-	0.21	-	oz.	
Mounting torque			6 (5)	-	1.2 (10)	kgf. cm (lbf · in)	
Made and the		Case style: TO-247AD 2L		EPU6006LH			
Marking device		Case style: TO-247AD 3L		APU6006LH			

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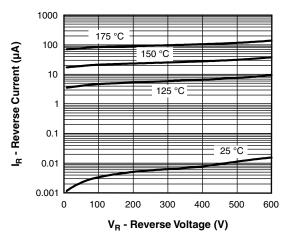


Fig. 1 - Typical Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

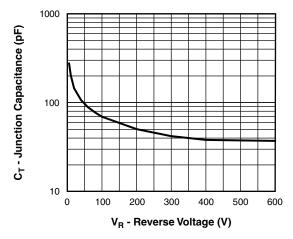


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

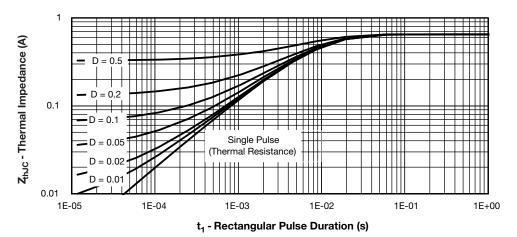


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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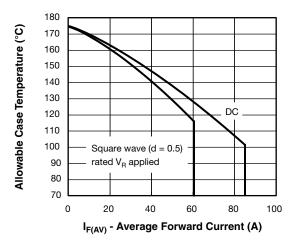


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

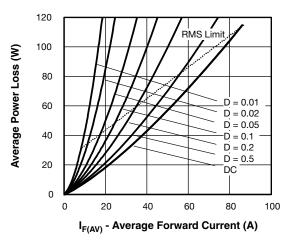


Fig. 6 - Forward Power Loss Characteristics

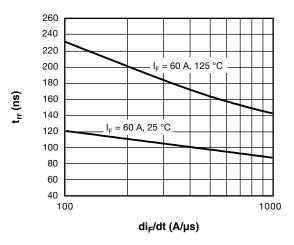


Fig. 7 - Typical Reverse Recovery Time vs. di_F/dt

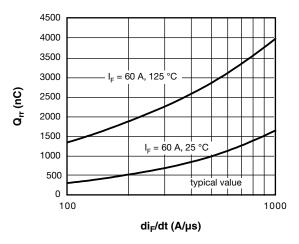
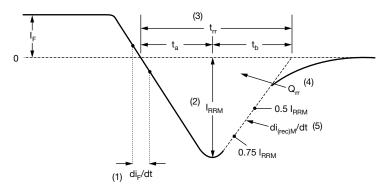


Fig. 8 - Typical Stored Charge vs. di_F/dt

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

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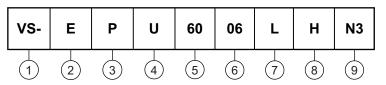


- (1) di_F/dt rate of change of current through zero crossing
 - t (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}
- (2) I_{RRM} peak reverse recovery current
- $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (5) di_{(rec)M}/dt peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- **2** Circuit configuration:
 - E = single diode 2 pins
 - A = single diode 3 pins
- **3** P = TO-247
- U = ultrafast recovery time
- 5 Current code (60 = 60 A)
- 6 Voltage code (06 = 600 V)
- 7 L = long lead
- 8 H = AEC-Q101 qualified
- 9 Environmental digit:

N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

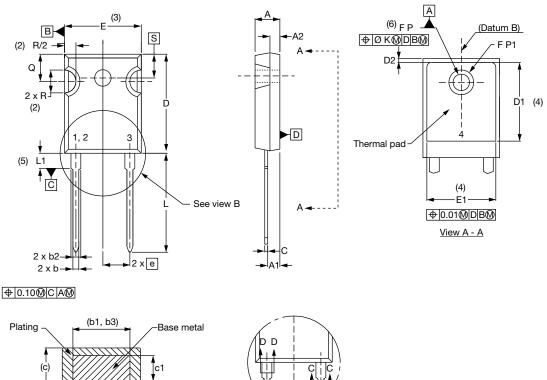
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-EPU6006LHN3	25	500	Antistatic plastic tube			
VS-APU6006LHN3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536			
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626			
Dout moulding information	TO-247AD 2L	www.vishay.com/doc?95648			
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007			

Vishay Semiconductors

TO-247AD 2L

DIMENSIONS in millimeters and inches



D D C C
<u>View B</u>

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

SYMBOL	MILLIMETERS		INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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